

General purpose (dual digital transistors)

EMD2 / UMD2N / IMD2A

●Features

- 1) Both the DTA124E chip and DTC124E chip in a EMT or UMT or SMT package.
- 2) Mounting possible with EMT3 or UMT3 or SMT3 automatic mounting machines.
- 3) Transistor elements are independent, eliminating interference.
- 4) Mounting cost and area can be cut in half.

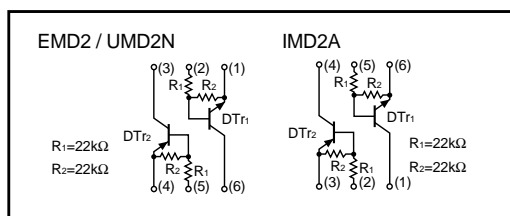
●Structure

Epitaxial planar type

NPN / PNP silicon transistor (Built-in resistor type)

The following characteristics apply to both the DTr1 and DTr2, however, the “-” sign on DTr2 values for the PNP type have been omitted.

●Equivalent circuit



●Absolute maximum ratings (Ta = 25°C)

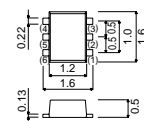
Parameter	Symbol	Limits	Unit
Supply voltage	V _{CC}	50	V
Input voltage	V _{IN}	40 -10	V
Output current	I _O	30	mA
	I _{C (Max.)}	100	
Power dissipation	Pd	150 (TOTAL)	mW *1
		300 (TOTAL)	mW *2
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-55~+150	°C

*1 120mW per element must not be exceeded.

*2 200mW per element must not be exceeded.

●External dimensions (Units : mm)

EMD2

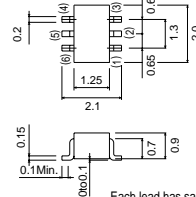


Each lead has same dimensions

ROHM : EMT6

Abbreviated symbol : D2

UMD2N



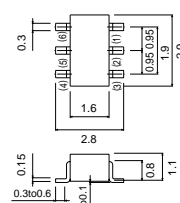
Each lead has same dimensions

ROHM : UMT6

EIAJ : SC-88

Abbreviated symbol : D2

IMD2A



Each lead has same dimensions

ROHM : SMT6

EIAJ : SC-74

Abbreviated symbol : D2

Transistors

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	—	—	0.5	V	$V_{CC}=5V, I_O=100\mu A$
	$V_{I(on)}$	3	—	—		$V_O=0.2V, I_O=10mA$
Output voltage	$V_{O(on)}$	—	0.1	0.3	V	$I_O=10mA, I_I=0.5mA$
Input current	I_I	—	—	0.36	mA	$V_I=5V$
Output current	$I_{O(off)}$	—	—	0.5	μA	$V_{CC}=50V, V_I=0V$
DC current gain	G_I	56	—	—	—	$V_O=5V, I_O=5mA$
Transition frequency	f_T	—	250	—	MHz	$V_{CE}=10mA, I_E=-5mA, f=100MHz$ *
Input resistance	R_I	15.4	22	28.6	$k\Omega$	—
Resistance ratio	R_2/R_1	0.8	1	1.2	—	—

* Transition frequency of the device

●Packaging specifications

Type	Package	Taping		
	Code	T2R	TR	T148
	Basic ordering unit (pieces)	8000	3000	3000
EMD2	○	—	—	—
UMD2N	—	○	—	—
IMD2A	—	—	—	○

●Electrical characteristic curves

DTr1 (NPN)

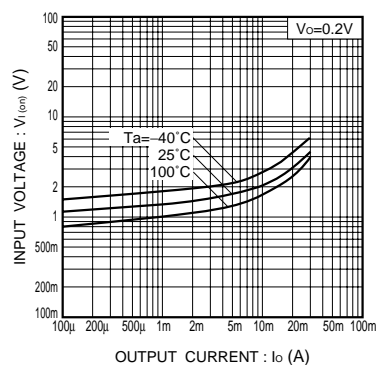


Fig.1 Input voltage vs. output current (ON characteristics)

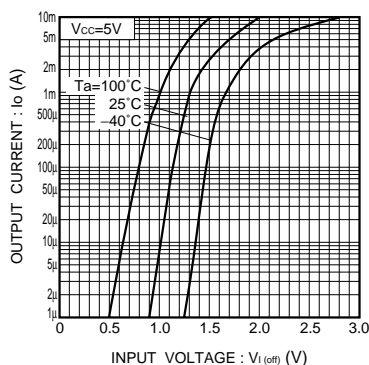


Fig.2 Output current vs. input voltage (OFF characteristics)

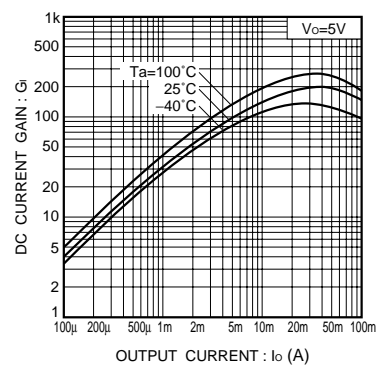


Fig.3 DC current gain vs. output current

Transistors

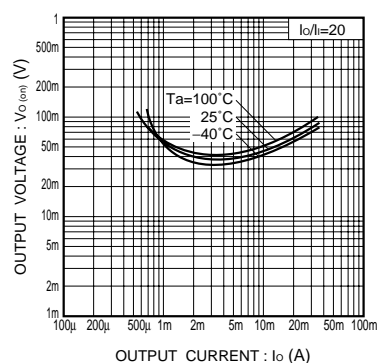


Fig.4 Output voltage vs. output current

DT₁₂ (PNP)

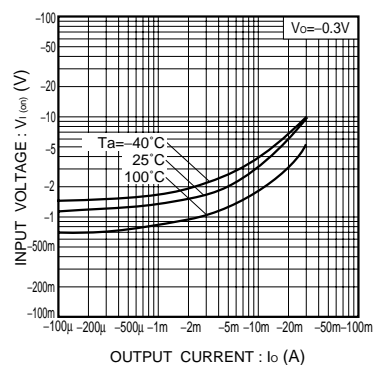


Fig.5 Input voltage vs. output current (ON characteristics)

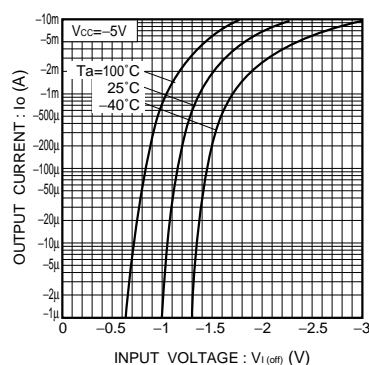


Fig.6 Output current vs. input voltage (OFF characteristics)

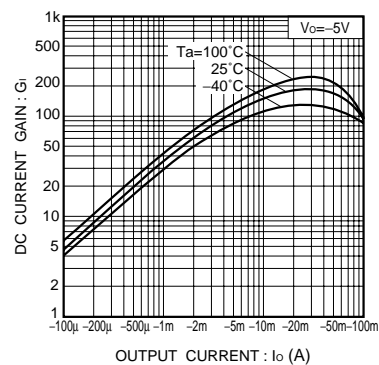


Fig.7 DC current gain vs. output current

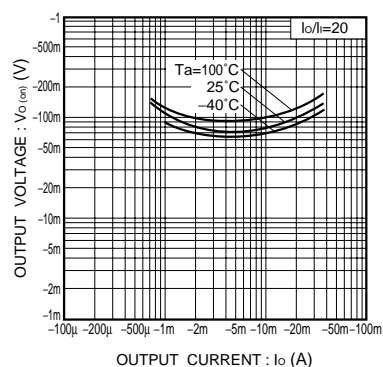


Fig.8 Output voltage vs. output current